

2SK2125

Silicon N-Channel Power F-MOS

■ Features

- Avalanche energy capability guaranteed : EAS > 15.6mJ
- $V_{GS}=\pm 30V$ guaranteed
- High-speed switching : $t_f=35ns$
- No secondary breakdown

■ Applications

- Non-contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator

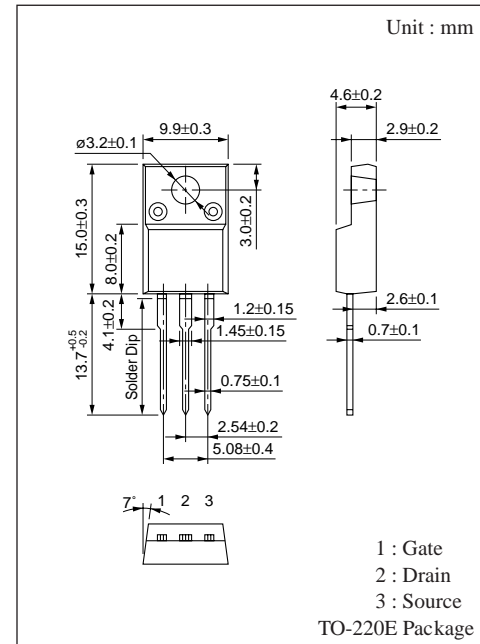
■ Absolute Maximum Ratings ($T_c = 25^\circ C$)

Parameter	Symbol	Rating	Unit
Drain-Source breakdown voltage	V_{DSS}	500	V
Gate-Source voltage	V_{GSS}	± 30	V
Drain current	DC	I_D	A
	Pulse	I_{DP}	A
Avalanche energy capability	EAS *	15.6	mJ
Allowable power dissipation	$T_C = 25^\circ C$	P_D	40
	$T_a = 25^\circ C$		2
Channel temperature	T_{ch}	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

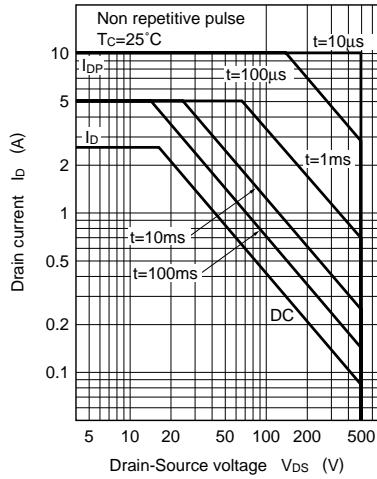
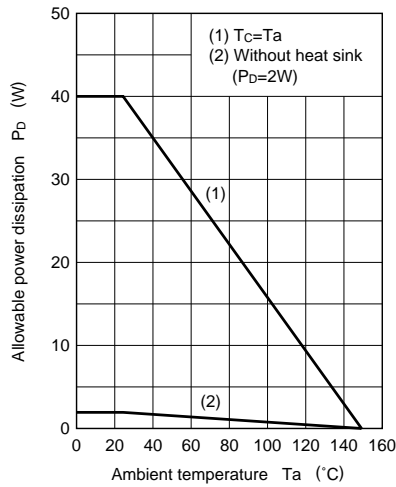
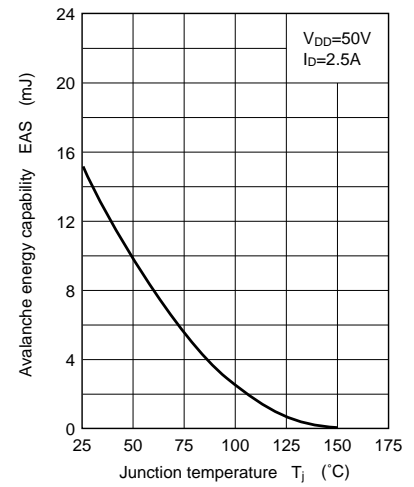
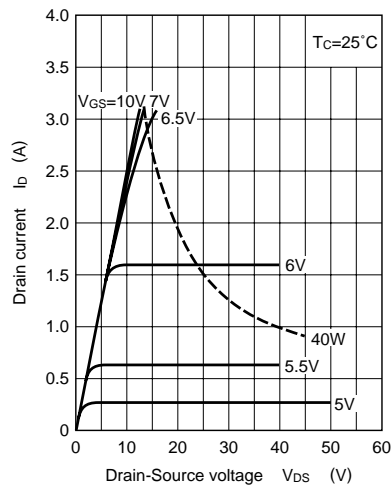
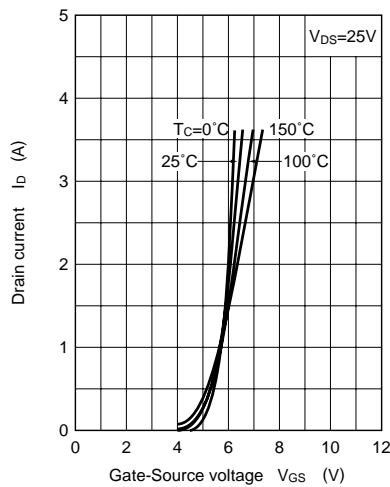
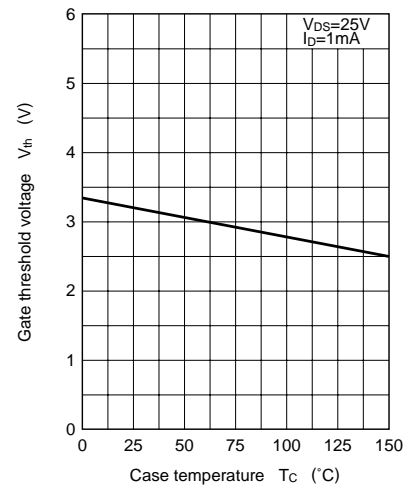
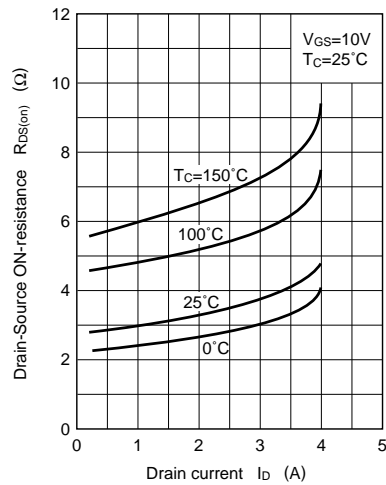
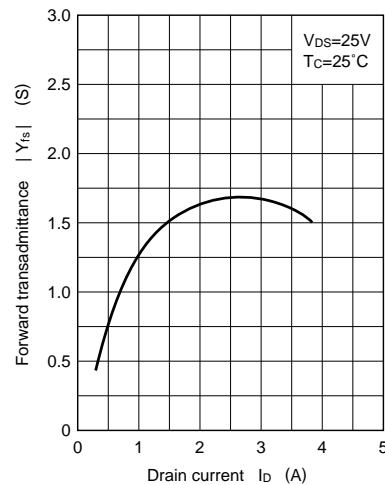
* $L=5mH$, $I_L=2.5A$, $V_{DD}=50V$, 1 pulse

■ Electrical Characteristics ($T_c = 25^\circ C$)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Drain-Source cut-off current	I_{DSS}	$V_{DS}=400V$, $V_{GS}=0$			0.1	mA
Gate-Source leakage current	I_{GSS}	$V_{GS}=\pm 30V$, $V_{DS}=0$			± 1	μA
Drain-Source breakdown voltage	V_{DSS}	$I_D=1mA$, $V_{GS}=0$	500			V
Gate threshold voltage	V_{th}	$V_{DS}=25V$, $I_D=1mA$	2		5	V
Drain-Source ON-resistance	$R_{DS(on)}$	$V_{GS}=10V$, $I_D=1.5A$		3.2	4	Ω
Forward transadmittance	$ Y_{fs} $	$V_{DS}=25V$, $I_D=1.5A$	1	1.5		S
Diode forward voltage	V_{DSF}	$I_{DR}=2.5A$, $V_{GS}=0$			-1.5	V
Input capacitance	C_{iss}	$V_{DS}=20V$, $V_{GS}=0$, $f=1MHz$		330		pF
Output capacitance	C_{oss}			55		pF
Feedback capacitance	C_{rss}			20		pF
Turn-on time (delay time)	$t_{d(on)}$	$V_{GS}=10V$, $I_D=1.5A$ $V_{DD}=150V$, $R_L=100\Omega$		15		ns
Rise time	t_r			25		ns
Fall time	t_f			30		ns
Turn-off time (delay time)	$t_{d(off)}$			55		ns
Channel-Case heat resistance	$R_{th(ch-c)}$				3.125	$^\circ C/W$



Area of safe operation (ASO)

 $P_D - T_a$  $EAS - T_j$  $I_D - V_{DS}$  $I_D - V_{GS}$  $V_{th} - T_C$  $R_{DS(on)} - I_D$  $|Y_{fs}| - I_D$  $I_{DR} - V_{DSF}$ 